

L Number	Hits	Search Text	DB	Time stamp
1	0	(led or (light adj emitting adj diode)) and (plated adj recess) and 257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/05 14:33
2	3	(led or (light adj emitting adj diode)) and (plated adj recess)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/05 14:15
3	21	(plated adj recess) and 257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/05 14:22
4	2	(ellipsoidal adj dome) and 257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/05 14:26
5	0	(elliptical adj encapsulant) and 257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/05 14:24
6	0	(ellipsoidal adj encapsulant) and 257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/05 14:26
7	20	(led or (light adj emitting adj diode)) and (vias adj through adj substrate) and 257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/05 14:58
8	87	(package) and (vias adj through adj substrate) and 257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/05 14:43
9	40	(package) and (vias adj through adj substrate) and recess	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/05 14:43
10	308	(led or (light adj emitting adj diode)) and (package) and recess and 257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/05 14:59

L Number	Hits	Search Text	DB	Time stamp
1	0	(first adj second adj interconnections)	USPAT;	2002/11/03 09:01
2	144	with (substrate adj surface) with led led with ((metallic or metal) adj layer)	US-PGPUB	
3	0	encapsulant adj size adj substrate	USPAT;	2002/11/03 10:09
4	0	encapsulant adj length adj substrate	US-PGPUB	
5	0	encapsulant with (length adj substrate)	USPAT;	2002/11/03 10:10
6	1	encapsulant with (width adj substrate)	US-PGPUB	
-	0	("(semiconductor adj laser) and iiiv").PN.	USPAT;	2002/11/03 10:10
-	0	("(semiconductor adj laser) and (iii adj v)").PN.	US-PGPUB	
-	0	("(semiconductor adj laser) and gallium").PN.	USPAT;	2002/11/02 11:17
-	9	(semiconductor adj laser) and iiiv	US-PGPUB	
-	0	((semiconductor adj laser) and iiiv) and (edge adj emitter)	USPAT;	2002/11/02 11:17
-	3	((semiconductor adj laser) and iiiv) and edge	US-PGPUB	
-	1	6069440.pn.	USPAT;	2002/11/02 11:18
-	1	6045240.pn.	US-PGPUB	
-	18	encapsulated adj light adj emitting adj diode	USPAT;	2002/11/02 11:21
-	0	(encapsulated adj light adj emitting adj diode) with transparent	US-PGPUB	
-	0	(transparent adj encapsulated adj material) adj substrate	USPAT;	2002/11/02 13:30
-	0	transparent adj encapsulated adj material	US-PGPUB	
-	87	transparent adj encapsulat\$	USPAT;	2002/11/02 13:30
-	17	(transparent adj encapsulat\$) and led	US-PGPUB	
			USPAT;	2002/11/02 13:37
			US-PGPUB	
			USPAT;	2002/11/02 13:41
			US-PGPUB	
			USPAT;	2002/11/02 13:39
			US-PGPUB	
			USPAT;	2002/11/02 13:41
			US-PGPUB	
			USPAT;	2002/11/02 13:42
			US-PGPUB	
			USPAT;	2002/11/02 13:43
			US-PGPUB	
			USPAT;	2002/11/03 08:58
			US-PGPUB	